

# PS7431-1A

## 4-PIN SOP HIGH ISOLATION VOLTAGE 3 000 Vr.m.s 1-ch Optical Coupled MOS FET

## DESCRIPTION

The PS7431-1A is a solid state relay containing GaAs a LED on the light emitting side (input side) and normally open (N.O.) contact MOS FETs on the output side.

It is suitable for analog signal control because of its low offset and high linearity.

#### FEATURES

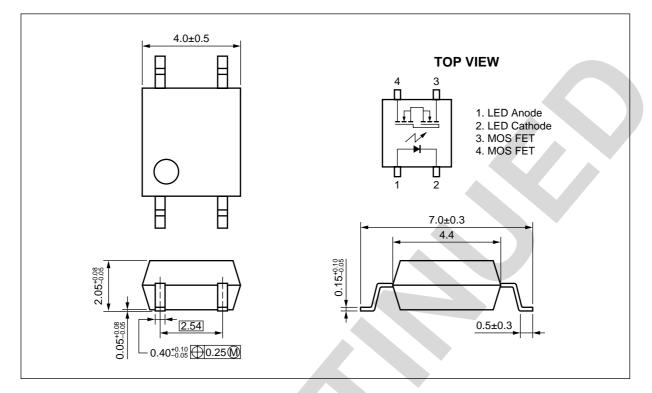
- High isolation voltage (BV = 3 000 Vr.m.s)
- Small and thin package (4-pin SOP, Height = 2.1 mm)
- 1 channel type (1 a output)
- Low LED operating current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Low offset voltage
- Ordering number of taping product: PS7431-1A-E3, E4, F3, F4
- UL approved: File No. E72422
- BSI approved: No. 8767/8768
- CSA approved: No. CA 101391

## **APPLICATIONS**

- Laptop PC, PDA
- Modem card
- Telephone, FAX
- Measurement equipment

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

## PACKAGE DIMENSIONS (UNIT: mm)



Part Number	Package	Packing Style	Application Part Number <sup>*1</sup>
PS7431-1A	4-pin SOP	Magazine case 100 pcs	PS7431-1A
PS7431-1A-E3		Embossed Tape 900 pcs/reel	
PS7431-1A-E4			
PS7431-1A-F3		Embossed Tape 3 500 pcs/reel	
PS7431-1A-F4			

## **ORDERING INFORMATION (Solder Contains Lead)**

\*1 For the application of the Safety Standard, following part number should be used.

## **ORDERING INFORMATION (Pb-Free)**

Part Number	Package	Packing Style	Application Part Number <sup>*1</sup>
PS7431-1A-A	4-pin SOP	Magazine case 100 pcs	PS7431-1A
PS7431-1A-E3-A		Embossed Tape 900 pcs/reel	
PS7431-1A-E4-A			
PS7431-1A-F3-A		Embossed Tape 3 500 pcs/reel	
PS7431-1A-F4-A			

\*1 For the application of the Safety Standard, following part number should be used.

## ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit		
Diode	Diode Forward Current (DC)		50	mA		
	Reverse Voltage	VR	5.0	V		
	Power Dissipation	PD	50	mW		
	Peak Forward Current *1	IFP	1	А		
MOS FET	Break Down Voltage	VL	350	V		
	Continuous Load Current	IL.	120	mA		
	Pulse Load Current <sup>*2</sup> (AC/DC Connection)	Ilp	240	mA		
	Power Dissipation	PD	310	mW		
Isolation Vo	Isolation Voltage *3		3 000	Vr.m.s.		
Total Power Dissipation		Ρτ	360	mW		
Operating Ambient Temperature		TA	-40 to +85	°C		
Storage Temperature		Tstg	-40 to +100	°C		

\***1** PW = 100 μs, Duty Cycle = 1%

\*2 PW = 100 ms, 1 shot

\*3 AC voltage for 1 minute at  $T_A = 25^{\circ}C$ , RH = 60% between input and output

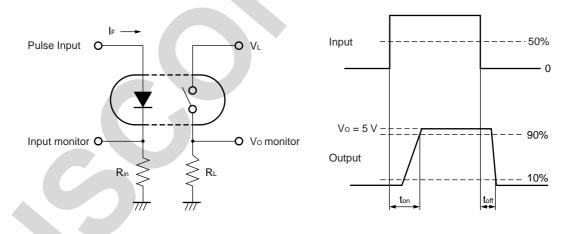
## **RECOMMENDED OPERATING CONDITIONS (TA = 25°C)**

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

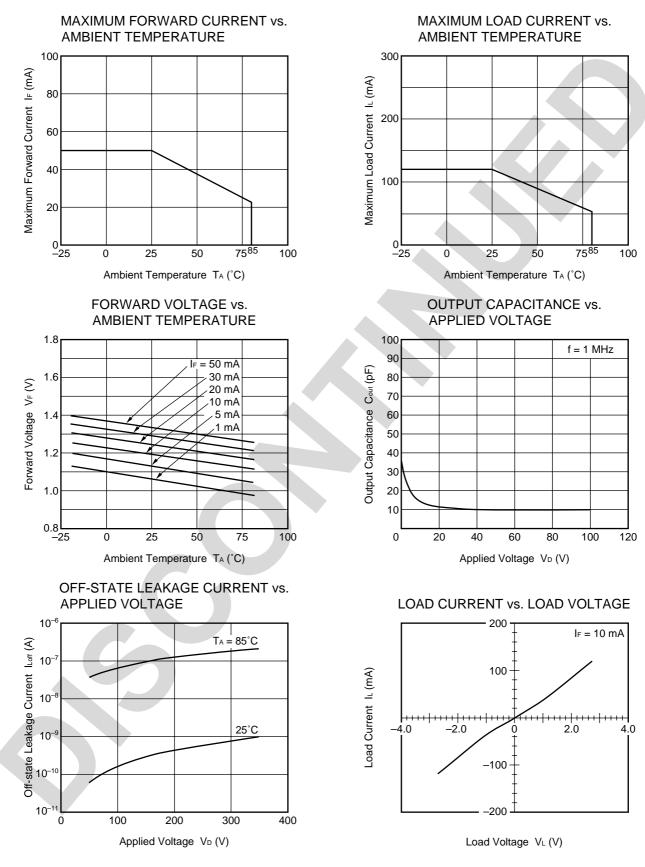
## ELECTRICAL CHARACTERISTICS (TA = 25°C)

ELECTRICAL CHARACTERISTICS (TA = 25°C)							
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	Vf	IF = 10 mA		1.2	1.4	V
	Reverse Current	IR	V <sub>R</sub> = 5 V			5.0	μA
MOS FET	Off-state Leakage Current	Loff	V <sub>D</sub> = 350 V		0.03	1.0	μA
	Output Capacitance	Cout	V <sub>D</sub> = 0 V, f = 1 MHz		35		pF
Coupled	LED On-state Current	IFon	I∟ = 120 mA			2.0	mA
	On-state Resistance	Ron1	I⊧ = 10 mA, I∟ = 10 mA		26	33	Ω
		Ron2	$I_F = 10 \text{ mA}, I_L = 120 \text{ mA}, t \le 10 \text{ ms}$		20	26	
	Turn-on Time <sup>*1</sup>	ton	IF = 10 mA, Vo = 5 V, RL = 500 Ω,		0.3	2.0	ms
	Turn-off Time <sup>*1</sup>	t <sub>off</sub>	PW ≥ 10 ms		0.07	0.2	
	Isolation Resistance	Ri-o	VI-O = 1.0 kVDC	10 <sup>9</sup>			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1 MHz		0.5		pF

#### \*1 Test Circuit for Switching Time



## TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)

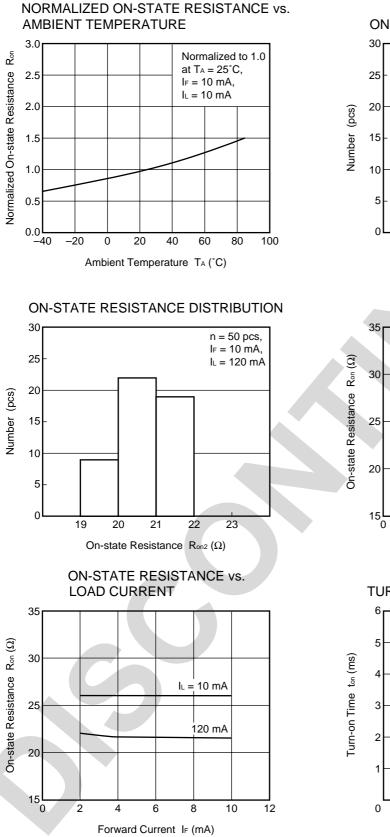


**Remark** The graphs indicate nominal characteristics.

n = 50 pcs,

IF = 10 mA,

l∟ = 10 mA



ON-STATE RESISTANCE DISTRIBUTION

25

26

ON-STATE RESISTANCE vs. LOAD CURRENT

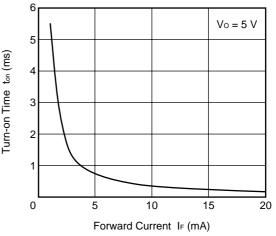
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On-state Resistance Ron1 (Ω)

28

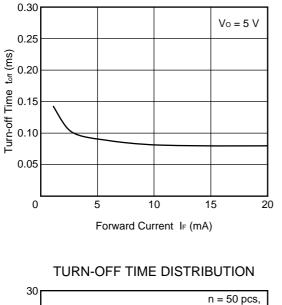
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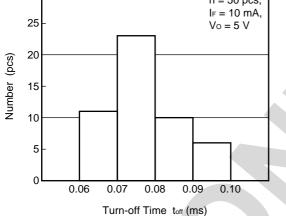
## TURN-ON TIME vs. FORWARD CURRENT

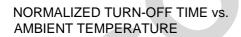


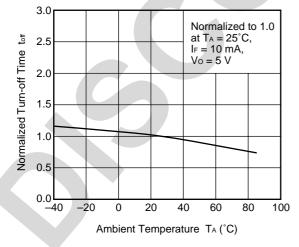
Remark The graphs indicate nominal characteristics.





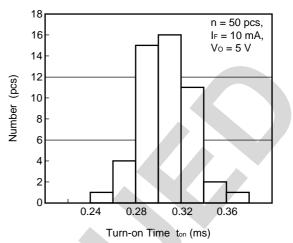


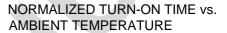


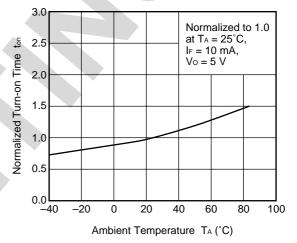


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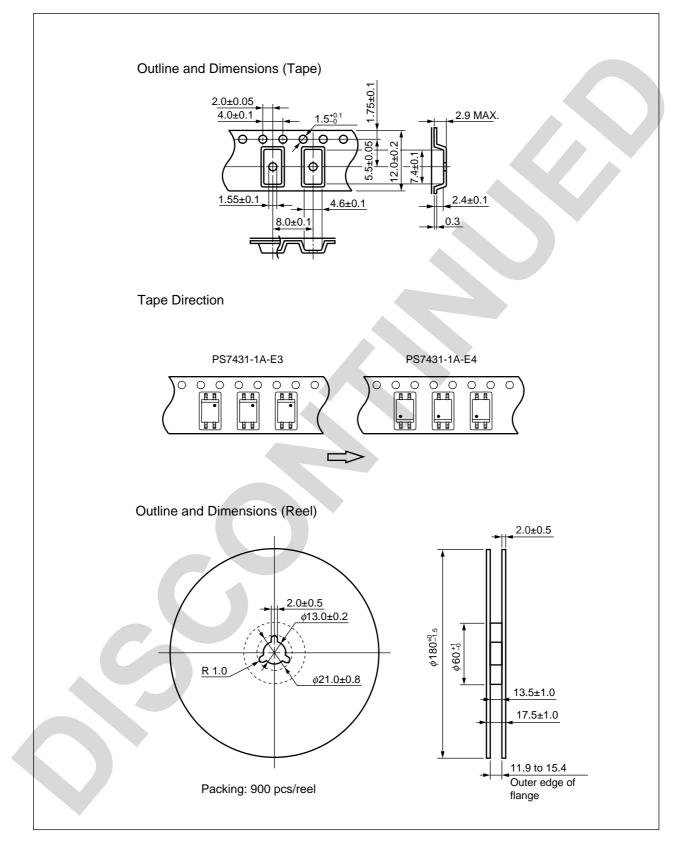
TURN-ON TIME DISTRIBUTION

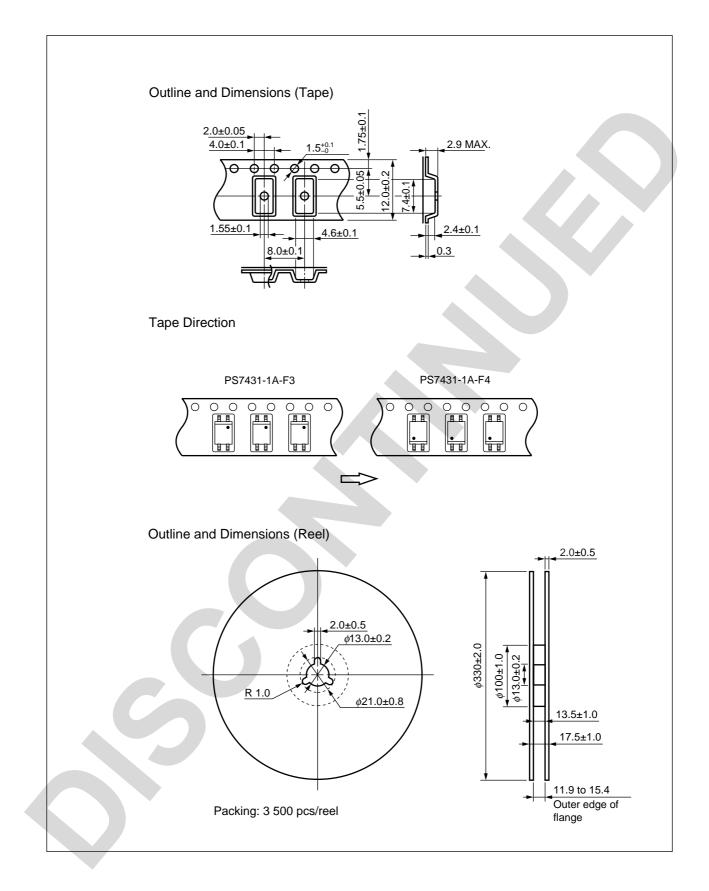






## **TAPING SPECIFICATIONS (in millimeters)**





## **RECOMMENDED SOLDERING CONDITIONS**

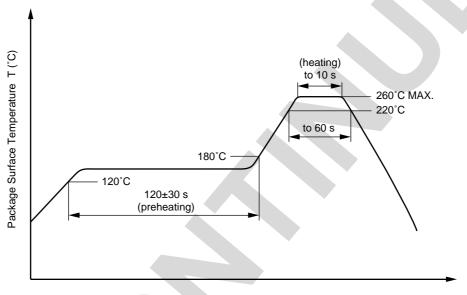
## (1) Infrared reflow soldering

- Peak reflow temperature
- Time of peak reflow temperature
- Time of temperature higher than 220°C
- Time to preheat temperature from 120 to 180°C
- Number of reflows
- Flux

260°C or below (package surface temperature) 10 seconds or less 60 seconds or less 120±30 s Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### Recommended Temperature Profile of Infrared Reflow



Time (s)

## (2) Wave soldering

- Temperature
- Time
- Preheating conditions
- Number of times
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

## (3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

260°C or below (molten solder temperature)

120°C or below (package surface temperature)

10 seconds or less

One



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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
РВВ	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

See CEL Terms and Conditions for additional clarification of warranties and liability.

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